UNR5225

Silicon NPN epitaxial planer type

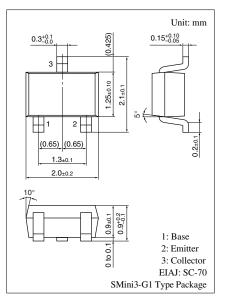
For muting circuit

Features

- \bullet Low collector to emitter saturation voltage $V_{\mbox{CE(sat)}}$
- Built-in resistor, allowing reduction of the number of parts.

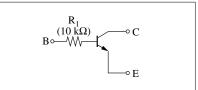
| Parameter | Symbol | Rating | Unit | | | |
|------------------------------|------------------|-------------|------|--|--|--|
| Collector to base voltage | V _{CBO} | 30 | V | | | |
| Collector to emitter voltage | V _{CEO} | 20 | V | | | |
| Emitter to base voltage | V _{EBO} | 5 | V | | | |
| Collector current | I _C | 600 | mA | | | |
| Total power dissipation | P _T | 150 | mW | | | |
| Junction temperature | Tj | 150 | °C | | | |
| Storage temperature | T _{stg} | -55 to +150 | °C | | | |

Absolute Maximum Ratings $T_a = 25^{\circ}C$



Marking Symbol: FZ

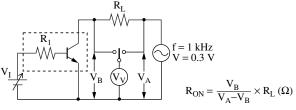
Internal Connection

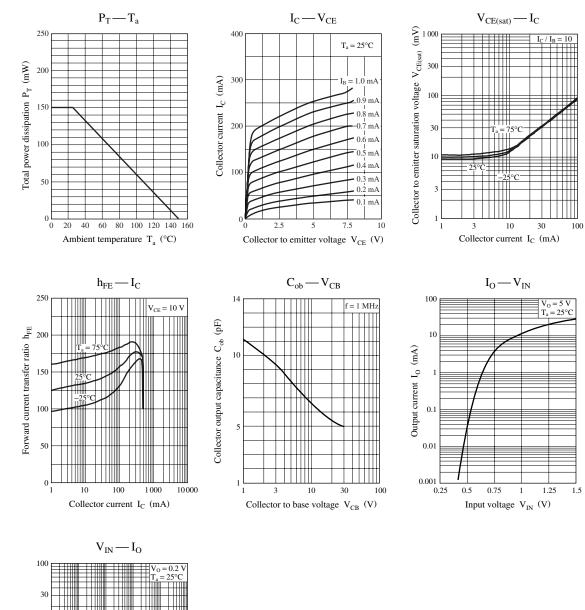


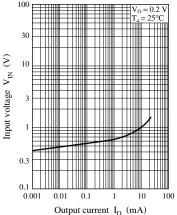
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|-----------------------------------------|----------------------|--------------------------------------------------------------------|------|-----|------|------|
| Collector to base voltage | V _{CBO} | $I_{\rm C} = 1 \ \mu A, \ I_{\rm E} = 0$ | 30 | | | V |
| Collector to emitter voltage | V _{CEO} | $I_{\rm C} = 1 {\rm mA}, I_{\rm B} = 0$ | 20 | | | V |
| Emitter to base voltage | V _{EBO} | $I_E = 1 \ \mu A, I_C = 0$ | 5 | | | V |
| Collector cutoff current | I _{CBO} | $V_{CB} = 30 \text{ V}, I_E = 0$ | | | 1 | μΑ |
| Emitter cutoff current | I _{EBO} | $V_{EB} = 5 V, I_C = 0$ | | | 1 | μΑ |
| Forward current transfer ratio | h _{FE} | $V_{CE} = 5 V, I_C = 50 mA$ | 100 | | 600 | |
| Collector to emitter saturation voltage | V _{CE(sat)} | $I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 2.5 \text{ mA}$ | | | 80 | mV |
| Input resistance | R ₁ | | -30% | 10 | +30% | kΩ |
| ON-resistance * | R _{ON} | $V_I = 7 V, R_L = 1 k\Omega, f = 1 kHz$ | | 1.5 | | Ω |
| Transition frequency | f _T | $V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$ | | 200 | | MHz |

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Note) *: R_{ON} measurement circuit







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